

MJL0281AG Datasheet

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DiGi Electronics Part Number MJL0281AG-DG

Manufacturer onsemi

Manufacturer Product Number MJL0281AG

Description TRANS NPN 260V 15A TO264

Detailed Description Bipolar (BJT) Transistor NPN 260 V 15 A 30MHz 180

W Through Hole TO-264



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DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MJL0281AG	onsemi
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	15 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
260 V	1V @ 500mA, 5A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10μA (ICBO)	75 @ 3A, 5V
Power - Max:	Frequency - Transition:
180 W	30MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-264-3, TO-264AA	TO-264
Base Product Number:	
MJL02	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
FAR99	8541 29 0075

MJL0281A (NPN) MJL0302A (PNP)

Preferred Devices

Complementary NPN-PNP Power Bipolar Transistors

These complementary devices are lower power versions of the popular MJL3281A and MJL1302A audio output transistors. With superior gain linearity and safe operating area performance, these transistors are ideal for high fidelity audio amplifier output stages and other linear applications.

Features

- Exceptional Safe Operating Area
- NPN/PNP Gain Matching within 10% from 50 mA to 3.0 A
- Excellent Gain Linearity
- High BVCEO
- High Frequency
- Pb-Free Packages are Available*

Benefits

- Reliable Performance at Higher Powers
- Symmetrical Characteristics in Complementary Configurations
- Accurate Reproduction of Input Signal
- Greater Dynamic Range
- High Amplifier Bandwith

Applications

- High-End Consumer Audio Products
 - Home Amplifiers
 - Home Receivers
- Professional Audio Amplifiers
 - Theater and Stadium Sound Systems
 - Public Address Systems (PAs)

MAXIMUM RATINGS

June, 2006 - Rev. 1

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	260	Vdc
Collector-Base Voltage	V_{CBO}	260	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	Vdc
Collector–Emitter Voltage – 1.5 V	V _{CEX}	260	Vdc
Collector Current – Continuous – Peak (Note 1)	I _C	15 30	Adc
Base Current – Continuous	Ι _Β	1.5	Adc
Total Power Dissipation @ T _C = 25°C	P_{D}	180	Watts
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

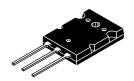
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle < 10%.

ON Semiconductor®

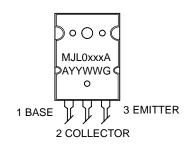
http://onsemi.com

15 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 260 VOLTS - 180 WATTS

TO-264 **CASE 340G** STYLE 2



MARKING DIAGRAM



MJL0xxxA = Device Code

xxx = 281 or 302

= Location Code

YY = Year \/\\/ = Work Week = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJL0281A	TO-264	25 Units/Rail
MJL0281AG	TO-264 (Pb-Free)	25 Units/Rail
MJL0302A	TO-264	25 Units/Rail
MJL0302AG	TO-264 (Pb-Free)	25 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

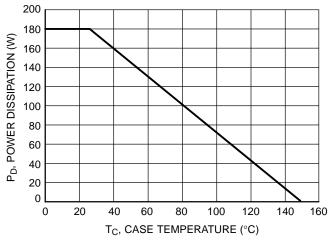
MJL0281A (NPN) MJL0302A (PNP)

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case		0.69	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
DFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage ($I_C = 30 \text{ mA}, I_B = 0$)	V _{CEO(sus)}	260	-	V
Collector Cutoff Current (V _{CB} = 260 V, I _E = 0)	Ісво	-	10	μΑ
Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0)	I _{EBO}	-	5.0	μΑ
ON CHARACTERISTICS				
DC Current Gain $(I_C = 0.5 \text{ A}, V_{CE} = 5.0 \text{ V})$ $(I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V})$ $(I_C = 3.0 \text{ A}, V_{CE} = 5.0 \text{ V})$	h _{FE}	75 75 75	150 150 150	-
Collector–Emitter Saturation Voltage $(I_C = 5.0 \text{ A}, I_B = 0.5 \text{ A})$	V _{CE(sat)}	-	1.0	V
Base–Emitter On Voltage (I _C = 5.0 A, V _{CE} = 5.0 V)	V _{BE(on)}	-	1.2	V
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product ($I_C = 1.0 \text{ A}, V_{CE} = 5.0 \text{ V}, f_{test} = 1.0 \text{ MHz}$)	f⊤	30	-	MHz
Output Capacitance (V _{CB} = 10 V, I _E = 0, f _{test} = 1.0 MHz)	C _{ob}	-	400	pF



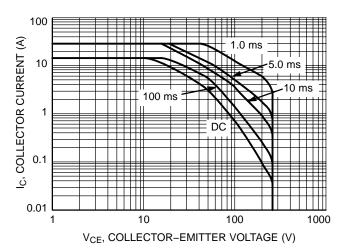


Figure 1. Power Derating

Figure 2. Safe Operating Area

MJL0281A (NPN) MJL0302A (PNP)

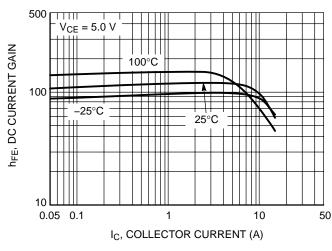


Figure 3. MJL0281A DC Current Gain

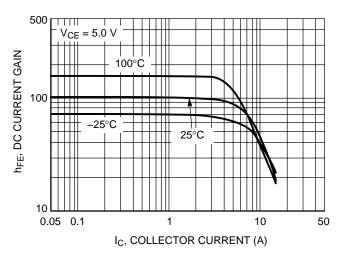


Figure 4. MJL0302A DC Current Gain

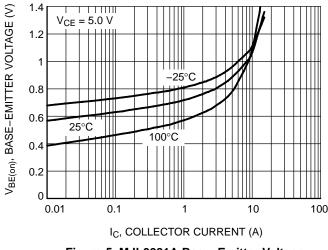


Figure 5. MJL0281A Base-Emitter Voltage

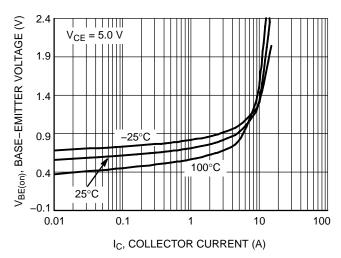


Figure 6. MJL0302A Base-Emitter Voltage

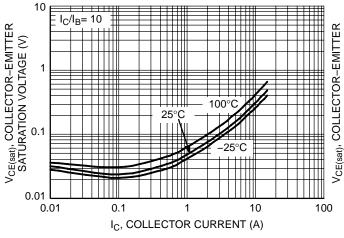


Figure 7. MJL0281A Saturation Voltage

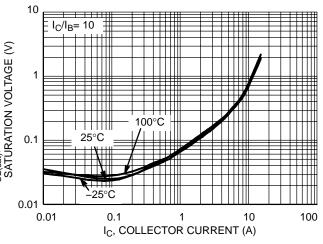


Figure 8. MJL0302A Saturation Voltage

MJL0281A (NPN) MJL0302A (PNP)

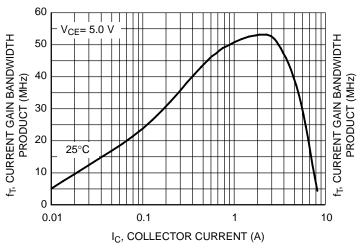


Figure 9. MJL0281A Current Gain Bandwidth Product

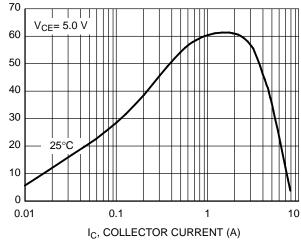
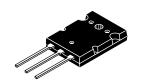


Figure 10. MJL0302A Current Gain Bandwidth Product



MECHANICAL CASE OUTLINE

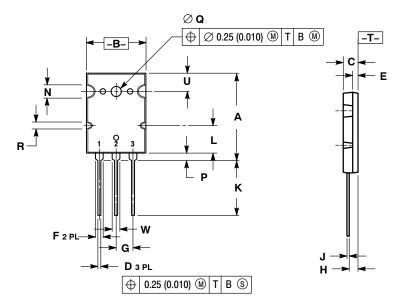
PACKAGE DIMENSIONS



TO-3BPL (TO-264) CASE 340G-02 **ISSUE J**

DATE 17 DEC 2004

SCALE 1:2



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	28.0	29.0	1.102	1.142	
В	19.3	20.3	0.760	0.800	
С	4.7	5.3	0.185	0.209	
D	0.93	1.48	0.037	0.058	
E	1.9	2.1	0.075	0.083	
F	2.2	2.4	0.087	0.102	
G	5.45 BSC		0.215 BSC		
Н	2.6	3.0	0.102	0.118	
J	0.43	0.78	0.017	0.031	
K	17.6	18.8	0.693	0.740	
L	11.2 REF		0.411 REF		
N	4.35	REF	0.172	0.172 REF	
P	2.2	2.6	0.087	0.102	
Q	3.1	3.5	0.122	0.137	
R	2.25 REF		0.089	REF	
U	6.3	.3 REF 0.248 REF		REF	
W	2.8	3.2	0.110	0.125	

GENERIC MARKING DIAGRAM*

STYLE 1: PIN 1. GATE 2. DRAIN

SOURCE

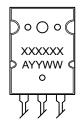
STYLE 2: PIN 1. BASE

2. COLLECTOR EMITTER

STYLE 3: PIN 1. GATE 2. SOURCE DRAIN

STYLE 4: PIN 1. DRAIN 2. SOURCE GATE 3.

STYLE 5: PIN 1. GATE 2. COLLECTOR EMITTER



XXXXXX = Specific Device Code

Α = Location Code

YY = Year WW = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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DESCRIPTION:	TO-3BPL (TO-264)		PAGE 1 OF 1	

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